NPN Planar Silicon Darlington Transistor



2SC3986

Driver Applications

Applications

· Suitable for use in switching of L load (motor drivers, printer hammer drivers, relay drivers).

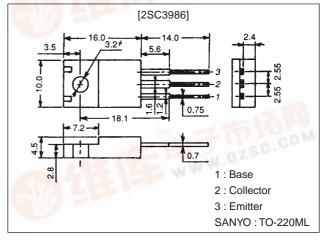
Features

- · High DC current gain.
- · Large current capacity and wide ASO.
- · On-chip Zener diode of 60±10V between collector and base.
- · Uniformity in collector-to-base breakdown voltage due to the adoption of an accurate impurity diffusion process.
- · High inductive load handling capability.
- · Micaless package facilitating mounting.

Package Dimensions

unit:mm

2041A



Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol Conditions		Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		50*	V
Collector-to-Emitter Voltage	V _{CEO}		50*	V
Emitter-to-Base Voltage	V _{EBO}	110	6	V
Collector Current	IC		2	Α
Collector Current (Pulse)	I _{CP}		4	А
Base Current	I _B	AND AND THE V	0.4	Α
Collector Dissipation	PC		2.0	W
		Tc=25°C	15	W
Junction Temperature	Tj	O Link	150	°C
Storage Temperature	Tstg	Co.	-55 to +150	°C

^{* :} With Zener diode (60±10V)

Electrical Characteristics at Ta = 25°C

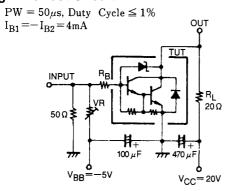
Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	I _{CBO}	V _{CB} =40V, I _E =0	100		10	μΑ
Emitter Cutoff Current	I _{EBO}	V _{EB} =5V, I _C =0		107	2	mA
DC Current Gain	hFE	V _{CE} =5V, I _C =1A	100	00 4000		
Gain-Bandwidth Product	fT	V _{CE} =5V, I _C =1A		180		MHz
Collector-to-Emitter Saturation Voltage	VCE(sat)	I _C =1A, I _B =4mA		1.0	1.5	V
Base-to-Emitter Saturation Voltage	V _{BE} (sat)	I _C =1A, I _B =4mA			2.0	V

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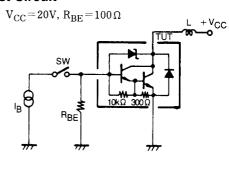
SANYO Electric Co.,Ltd. Semiconductor Bussiness Headquaters
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

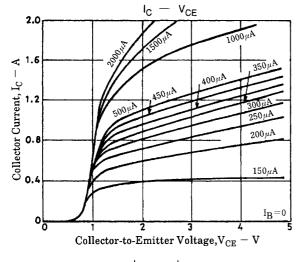
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =0.1mA, I _E =0	50	60	70	V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =1mA, R _{BE} =∞	50	60	70	V
Inductive Load Handling Capability	Es/b	L=100mH, R_{BE} =100 Ω	25			mJ
Turn-ON Time	ton	See specified Test Circuit. V _{CC} =20V, I _C =1A, I _{B1} =-I _{B2} =4mA		0.2		μs
Storage Time	t _{stg}	See specified Test Circuit. V _{CC} =20V, I _C =1A, I _{B1} =-I _{B2} =4mA		3.5		μs
Fall Time	t _f	See specified Test Circuit. VCC=20V, IC=1A, IB1=-IB2=4mA		0.5		μs

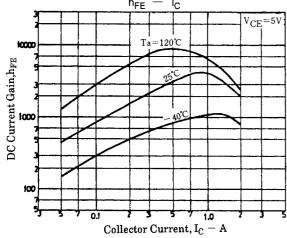
Switching Time Test Circuit

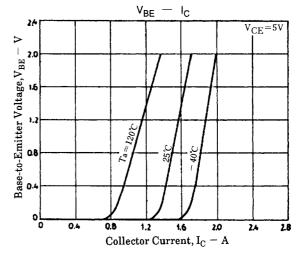


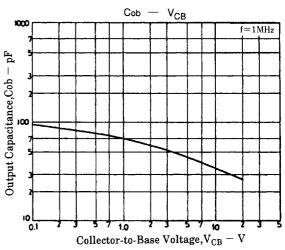
Es/b Test Circuit

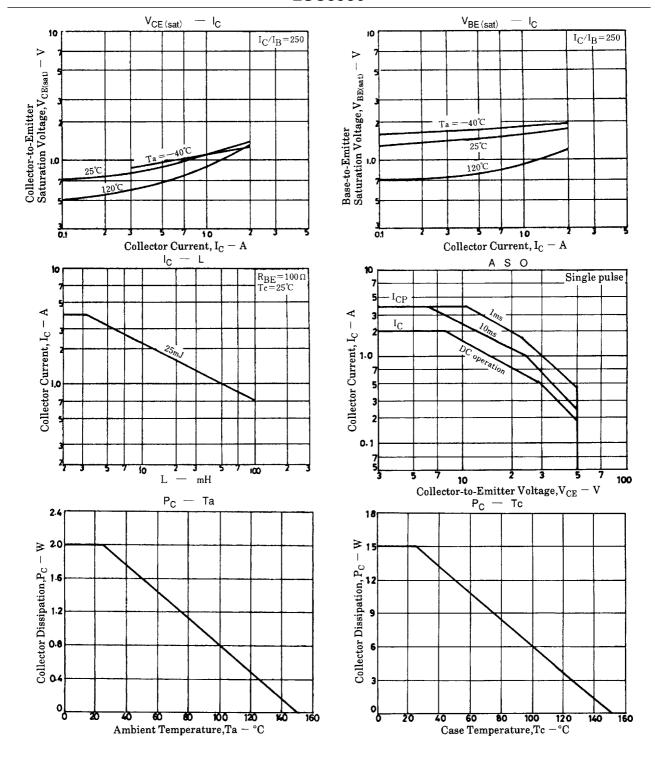












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